



LOW DROP VOLTAGE REGULATOR DRIVE FOR EXTERNAL N-CHANNEL POWER MOSFET

- The diagram illustrates two common integrated circuit (IC) package types: SO-8 and DIP-8. On the left, the SO-8 package is shown as a small, square, surface-mount component with eight pins extending from its sides. On the right, the DIP-8 package is shown as a larger, rectangular component with eight pins extending from its bottom. Below each package is its respective label: SO-8 and DIP-8.

The LPR30 is a very Low Dropout Regulator Controller in a single IC solution for higher current low dropout linear voltage regulator. It uses an external N-CHANNEL POWER MOSFET as the linear pass element. The LPR30 features a dropout voltage as low as the $R_{DS(ON)}$ of the external Power MOSFET multiplied by the output current. Consequently the output current can be as high as the POWER MOSFET can provide (also using an adequate heatsink).

The V_{CC} of the LPR30 range from 5V to 30V. For very low drop voltage operation, the LPR30 requires an external gate drive supply to provide the control voltage needed to drive the gate of the external POWER MOSFET.

- ULTRA HIGH CURRENT ULTRA LOW DROPOUT VOLTAGE REGULATOR
- CONSTANT HIGH CURRENT SOURCE
- LOW PARTS COUNT 5V TO 3.3V COMPUTER SUPPLY
- LOW NOISE/LOW DROP SMPS POST REGULATOR

TO GATE OF
POWMOS

Vcc 1

8

3 LIM -

2 LIM +

CURR LIM

7 ERR -

6 ERR +

ERR AMP

4 REF

REF

5

GND

SC10730

LPR30

The regulator output is constant-current limited when the controller detects 50mV across an external sense resistor.

It has an internal high precision ($\pm 2\%$) Voltage Reference at 2.5V

The output regulated voltage is possible to program to any voltage from 1V to more than 50V.

Flexible design is achieved by the availability of the Voltage Reference Output through an external pin (N.4) that is able to supply more than 20mA as load current. The LPR30 is available in 8 pin plastic DIP and in SO-8 for SMD. In both package versions it is able to operate from 0°C to 70°C.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	DC Input Voltage	36	V
I_{OREF}	Reference Output Current	Internally Limited	
P_{tot}	Power Dissipation	1	W
T_{op}	Operating Junction Temperature Range	0 to 70	°C
T_{stg}	Storage Temperature Range	-40 to 150	°C
V_{GATE}	Maximum Gate Voltage (pin n.8)	60	V
I_{GATE}	Maximum Gate Current (pin n.8)	200	mA

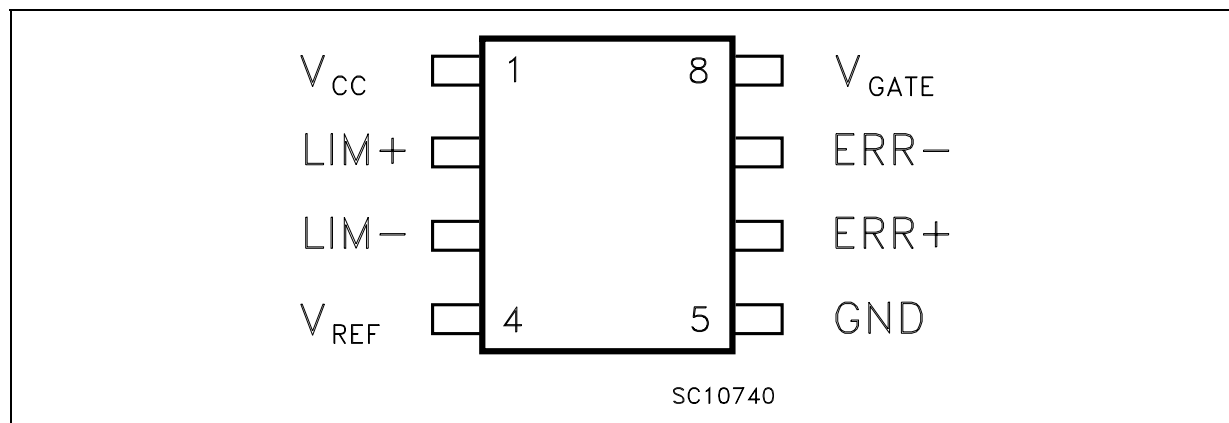
Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

THERMAL DATA

Symbol	Parameter	DIP-8	SO-8	Unit
$R_{thj-amb}$	Thermal Resistance Junction-ambient (*) Max	130 to 180	100 to 150	°C/W

(*) This value depends from thermal design of PCB on which the device is mounted.

CONNECTION DIAGRAM (top view)



ORDERING CODES

TYPE	DIP-8	SO-8	SO-8 (Tape & Reel)
LPR30	LPR30N	LPR30D	LPR30D-TR

ELECTRICAL CHARACTERISTICS (refer to the test circuits, $V_{CC} = 10V$, $T_J = 25^\circ C$, unless otherwise specified.)

GENERAL

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{CC}	Operating Supply Voltage		5		30	V
I_{CC}	Supply Current	$I_K = 0 \mu A$ $V_{CC} = 30 V$ $T_J = 0 \text{ to } 70^\circ C$ ERR(-), LIM(-) = 1V ERR(+), LIM(+) = 0V		2	4	mA
V_{OSAT}	Output Saturation Voltage	$V_{CC} = 5 V$ $I_O = 100 \text{ mA}$ $T_J = 0 \text{ to } 70^\circ C$ ERR(-), LIM(-) = 1V ERR(+), LIM(+) = 0V		280	500	mV
I_{OLK}	Output Leakage Current	$V_{CC} = 5 V$ $V_O = 60 V$ ERR(-), LIM(-) = 0V ERR(+), LIM(+) = 1V			100	μA

REFERENCE BLOCK

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{REF}	Reference Output Voltage		2.45	2.5	2.55	V
I_K	Reference Output Current		20			mA
$\Delta V_{REF} / \Delta I_K$	Reference Output Voltage Change	$I_K = 1 \text{ to } 20 \text{ mA}$ $C_{REF} = 0 \text{ pF}$		3		mV
SVR	Supply Voltage Rejection	$V_I < 10 V \pm 1 V$ $f = 120 \text{ Hz}$ $C_{REF} = 0 \text{ pF}$		70		dB
eN	Output Noise	$B = 10 \text{ Hz to } 10 \text{ KHz}$ $I_K = 10 \text{ mA}$ $C_{REF} = 0 \text{ pF}$		50		μV

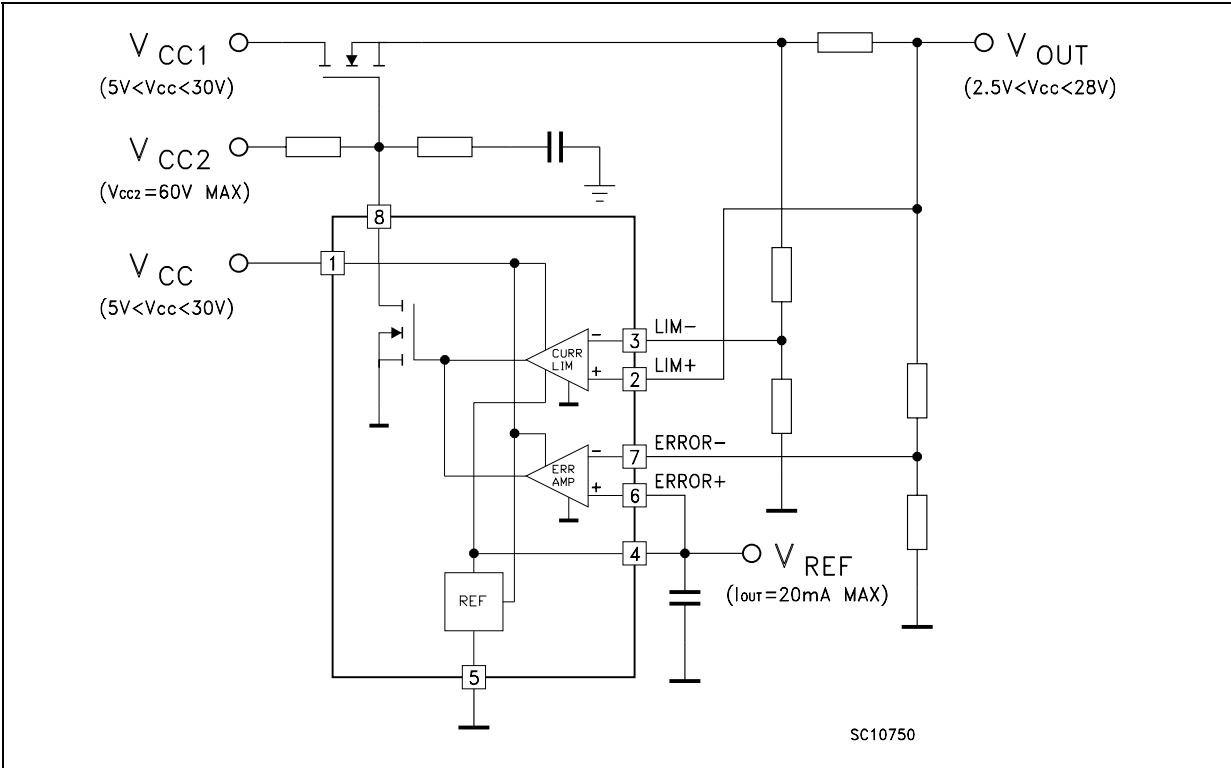
ERROR AMPLIFIER BLOCK

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_B	Input Bias Current			0.3	1	μA
V_{OS}	Input Offset Voltage	$V_{CC} = 5 \text{ to } 30 V$ $T_J = 0 \text{ to } 70^\circ C$			5	mV
I_{OS}	Input Offset Current			5	50	nA
G_V	Open Loop Gain	$T_J = 0 \text{ to } 70^\circ C$	80			dB
V_{CM}	Input Common Mode Voltage Range	$T_J = 0 \text{ to } 70^\circ C$	1		$V_{CC}-1$	V
CMR	Common Mode Rejection			70		dB
SVR	Supply Voltage Rejection	$V_I = 9 \text{ to } 11 V$ $f = 120 \text{ Hz}$	70			dB
		$V_I = 9 \text{ to } 11 V$ $f = 10 \text{ KHz}$	60			

CURRENT LIMITING BLOCK

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_B	Input Bias Current				0.5	μA
V_{OS}	Input Offset Voltage	$T_J = 0 \text{ to } 70^\circ C$	40		60	V
G_V	Open Loop Gain	$T_J = 0 \text{ to } 70^\circ C$	50			dB
V_{CM}	Input Common Mode Voltage Range	$T_J = 0 \text{ to } 70^\circ C$	0		$V_{CC}-3$	V

TEST CIRCUITS



TYPICAL PERFORMANCE CHARACTERISTICS

Figure 1 : Reference Output Voltage vs Temperature

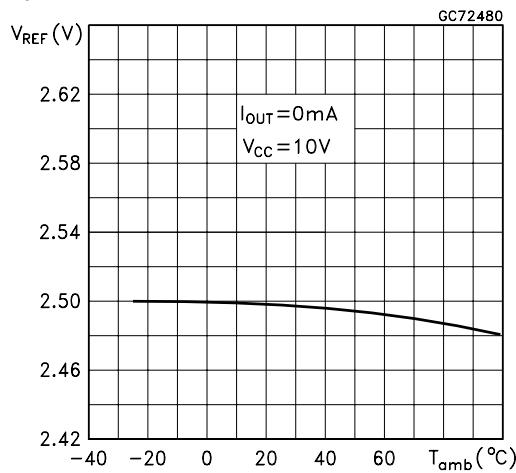


Figure 2 : Reference Output Voltage vs Load Current

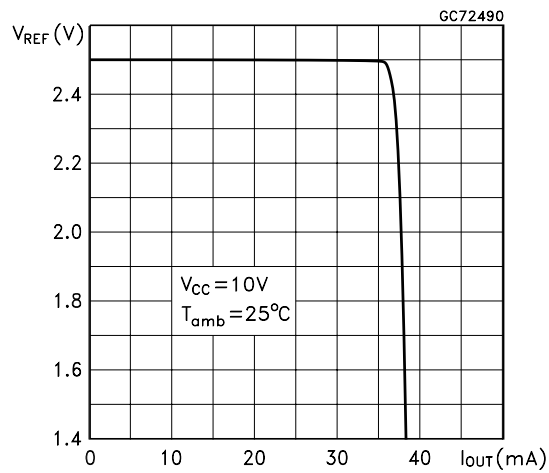
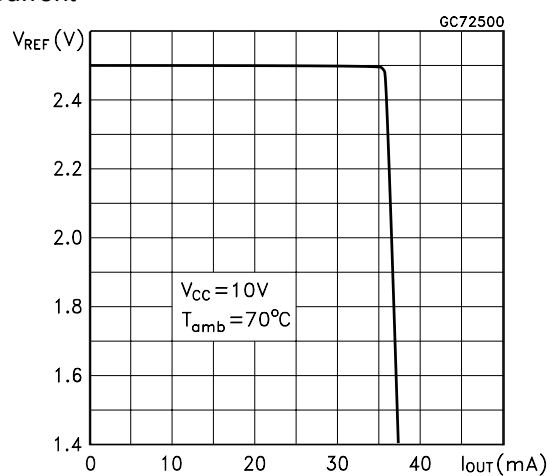
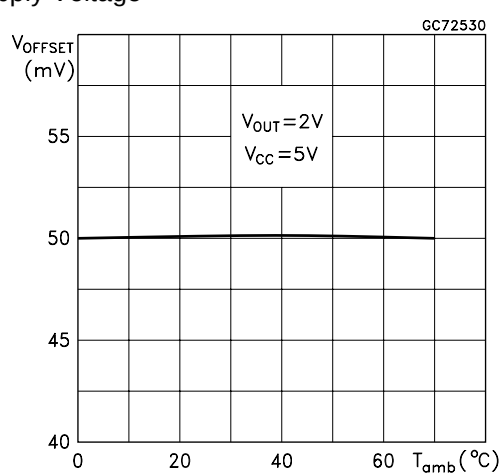
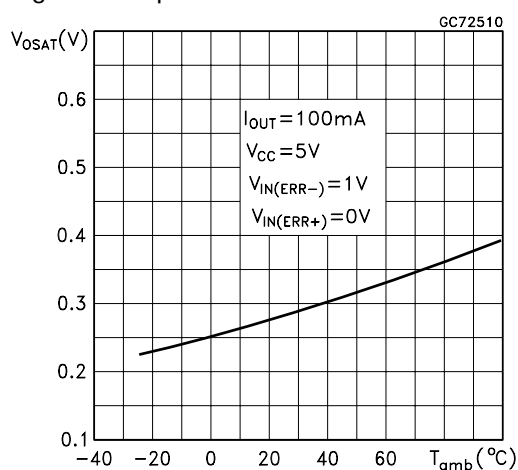
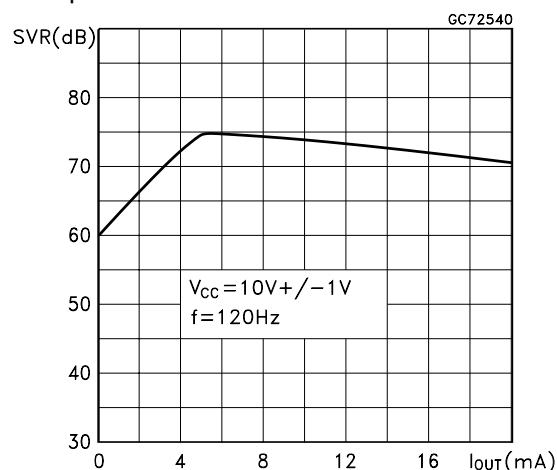
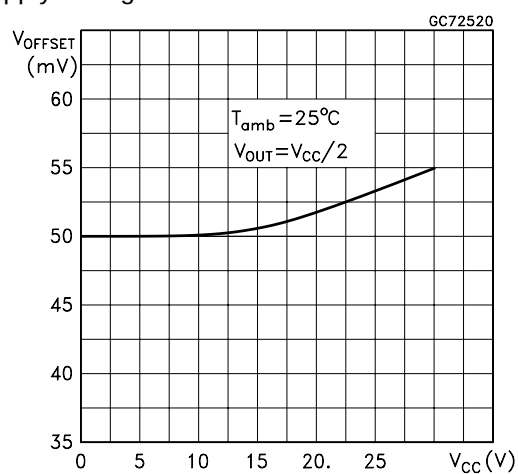
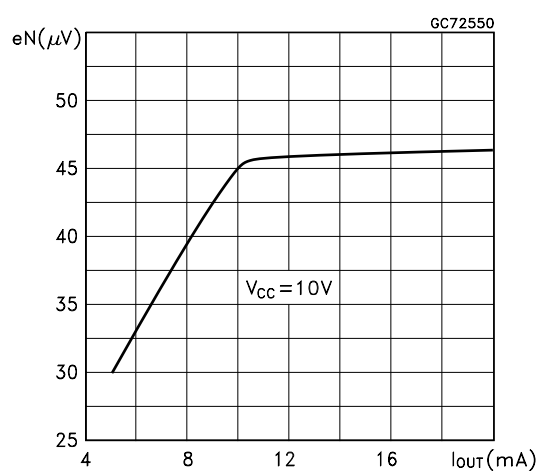


Figure 3 : Reference Output Voltage vs Load Current**Figure 6 : Current Limit Input Offset Voltage vs Supply Voltage****Figure 4 : Error Amplifier Output Saturation Voltage vs Temperature****Figure 7 : Reference Supply Voltage Rejection vs Output Current****Figure 5 : Current Limit Input Offset Voltage vs Supply Voltage****Figure 8 : Reference Output Noise vs Output Current**

APPLICATION INFORMATION

Figure 9 : LPR30 Typical Application

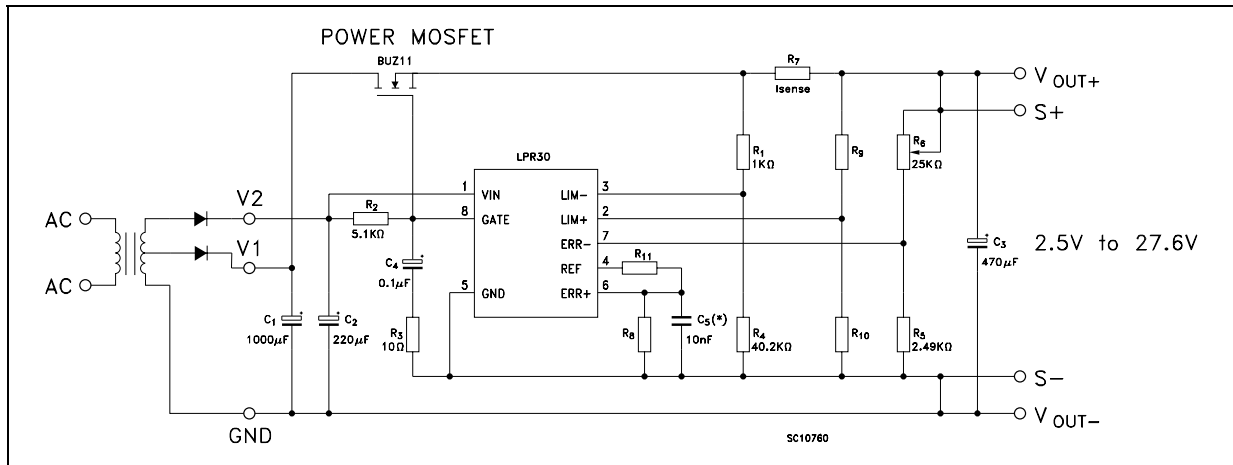
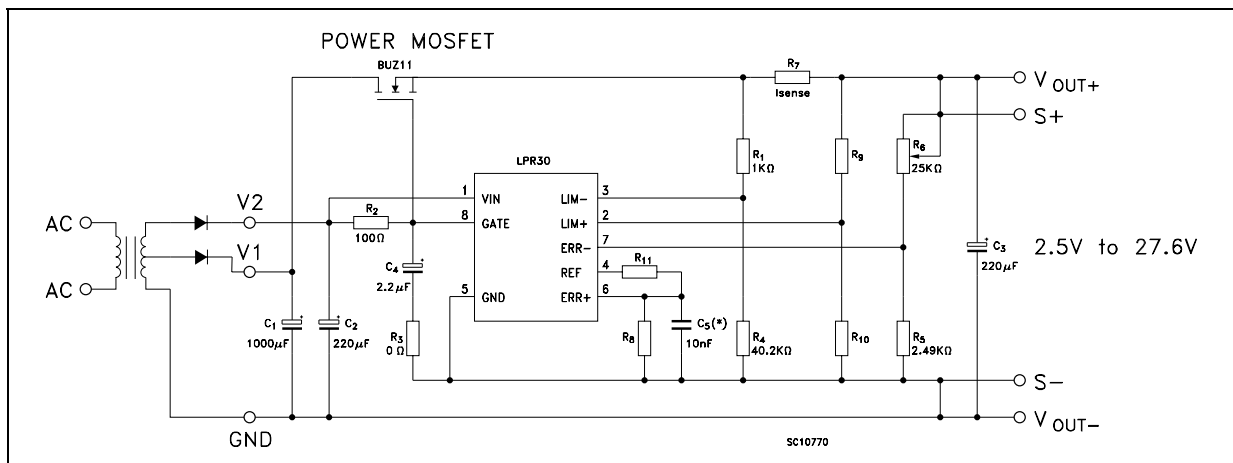
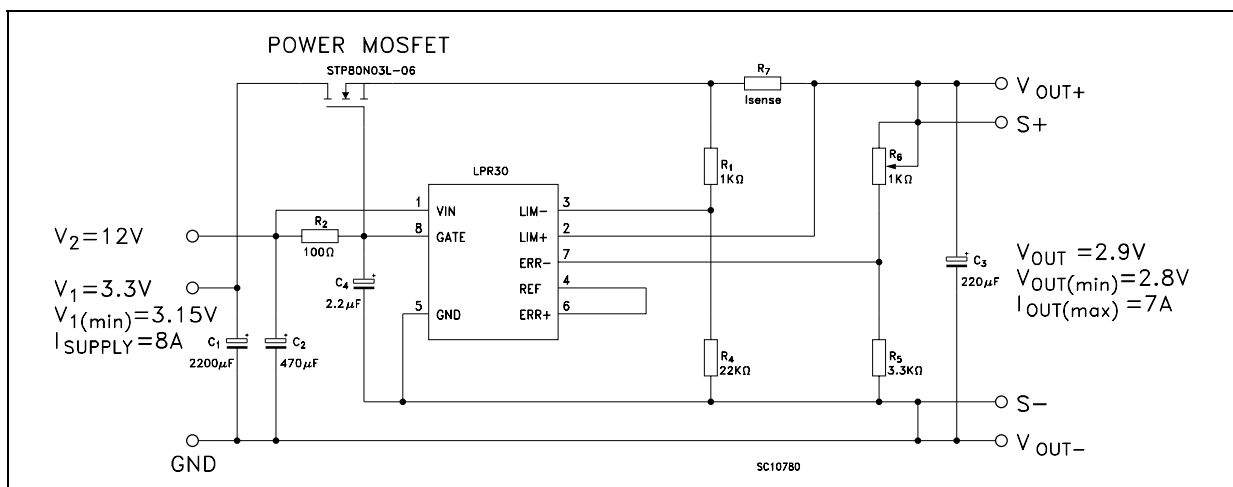
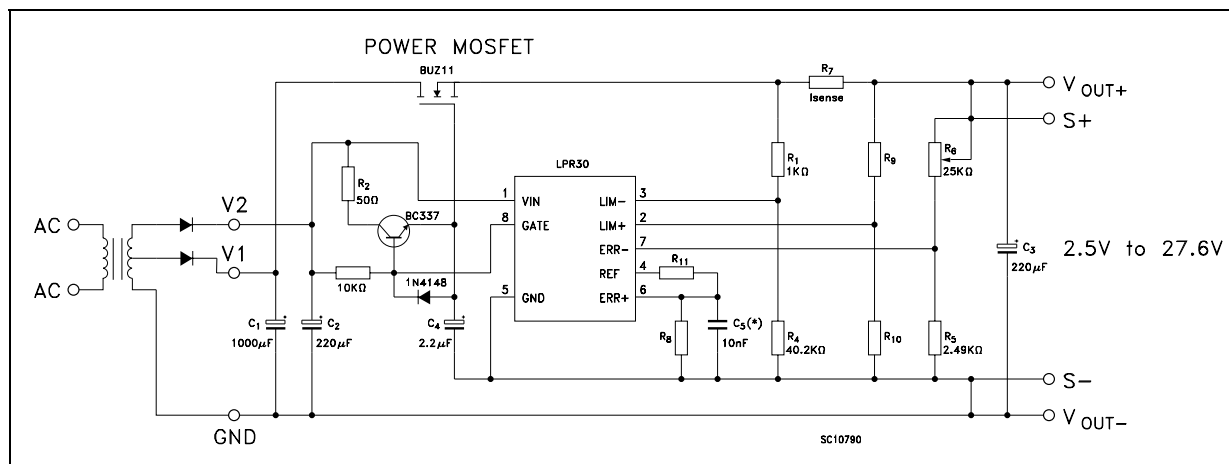
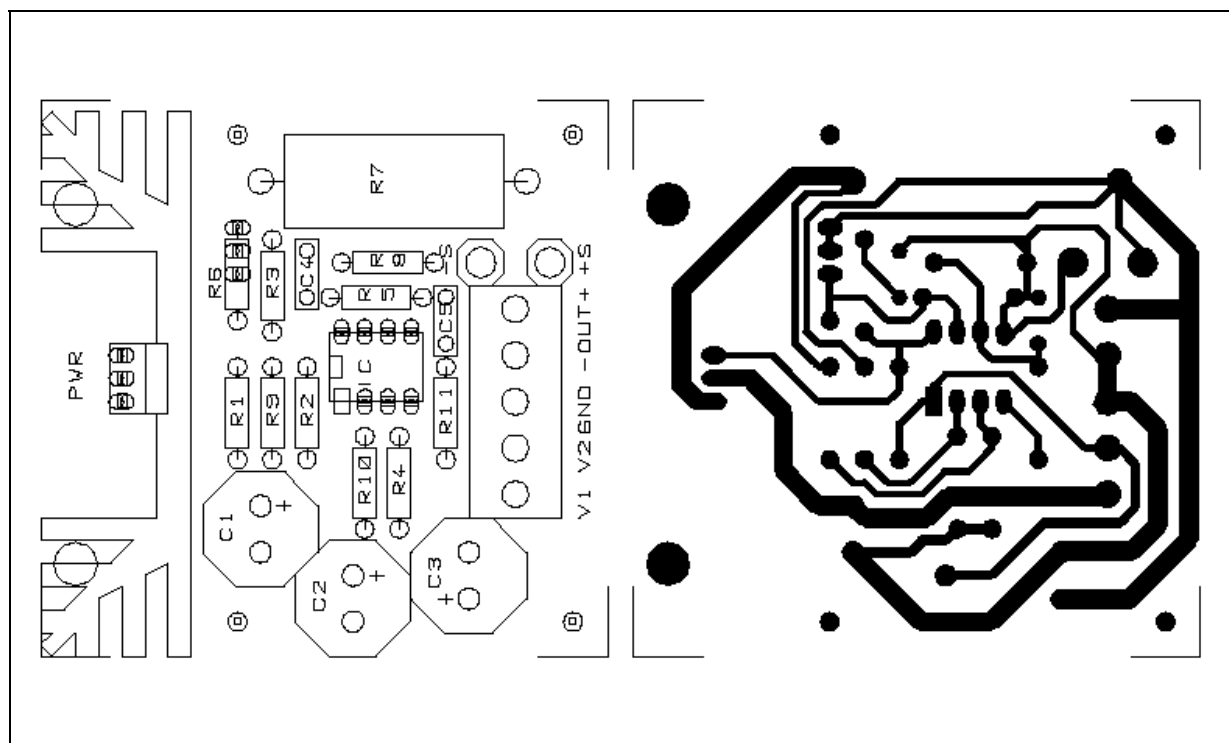


Figure 10 : Configuration For Faster Response

Figure 11 : Configuration For $V_I = 3.3V$, $V_O = 2.9V$, $I_O = 7A$ 

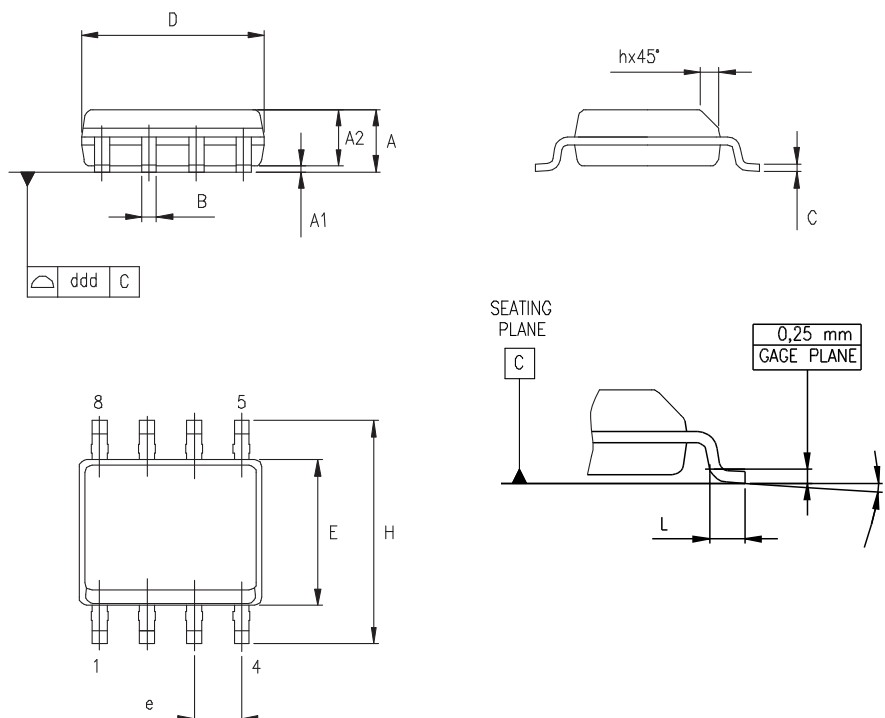
(*) This capacitor improves noise performance; can be omitted in most applications.

Figure 12 : Application For Very Fast Response Speed**STANDARD APPLICATION DEMOBOARD**

Note: This demoboard refers to the typical application shown in figure 9

SO-8 MECHANICAL DATA

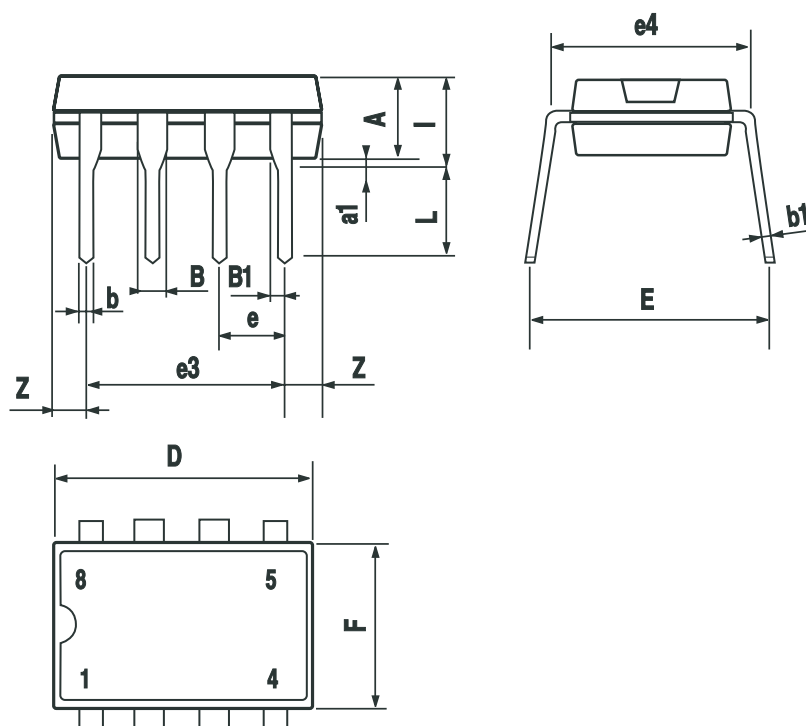
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.04		0.010
A2	1.10		1.65	0.043		0.065
B	0.33		0.51	0.013		0.020
C	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
E	3.80		4.00	0.150		0.157
e		1.27			0.050	
H	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	8° (max.)					
ddd			0.1			0.04



0016023/C

Plastic DIP-8 MECHANICAL DATA

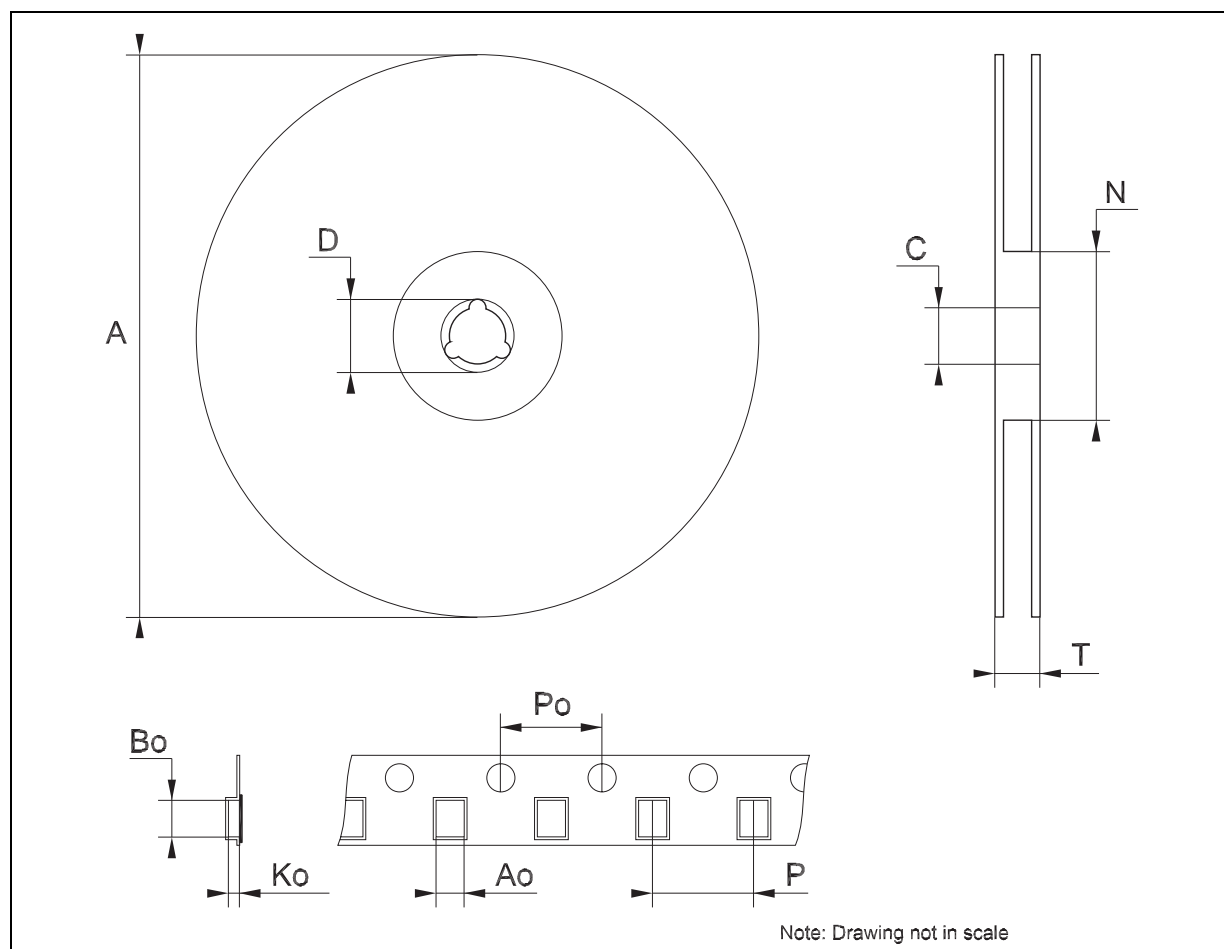
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A		3.3			0.130	
a1	0.7			0.028		
B	1.39		1.65	0.055		0.065
B1	0.91		1.04	0.036		0.041
b		0.5			0.020	
b1	0.38		0.5	0.015		0.020
D			9.8			0.386
E		8.8			0.346	
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			7.1			0.280
I			4.8			0.189
L		3.3			0.130	
Z	0.44		1.6	0.017		0.063



P001F

Tape & Reel SO-8 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Bo	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
P	7.9		8.1	0.311		0.319



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